



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

John MACNEIL

Group Art Unit: 1762

Serial No.: 10/638,424

Examiner: Unknown

Filed: August 12, 2003

Attorney Docket No. WLJ.068D

For: DIELECTRIC LAYER FOR A SEMICONDUCTOR DEVICE AND METHOD OF
PRODUCING THE SAME

REQUEST FOR CORRECTED FILING RECEIPT

U.S. Patent and Trademark Office
2011 South Clark Place
Customer Window, Mail Stop Application Number
Crystal Plaza Two, Lobby, Room 1B03
Arlington, VA 22202

Sir:

Attached is a copy of the official filing receipt from the PTO in the above application for
which issuance of a corrected filing receipt is respectfully requested.

Please correct the following data as follows:

Please change the Domestic Priority data as claimed by applicant to:

This application is a DIV of 09/942,933 08/31/2001

**which is a Continuation-in-part of application No. 09/914,204, filed as
application No. PCT/GB00/00671 on Feb. 24, 2000.**

Respectfully submitted,

VOLENTINE FRANCOS, PLLC


Adam C. Volentine
Registration No. 33289

12200 Sunrise Valley Drive, Suite 150
Reston, Virginia 20191
Telephone No.: (703) 715-0870
Facsimile No. (703) 715-0877

Dated: February 10, 2004



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/638,424	08/12/2003	1762	750	WLJ.068D	17	4	2

JONES VOLENTINE, P.L.L.C.
Suite 150
12200 Sunrise Valley Drive
Reston, VA 20191

CONFIRMATION NO. 5089

UPDATED FILING RECEIPT



OC000000011474053

Date Mailed: 12/11/2003

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

John MacNeil, Heath, UNITED KINGDOM;

Domestic Priority data as claimed by applicant

This application is a DIV of 09/942,933 08/31/2001 PAT 6,653,247
which is a Continuation-in-part of application No. 09/914,204,
filed as application No. PCT/GB00/00671 on Feb. 24, 2000.

Foreign Applications

UNITED KINGDOM 9904427.3 02/26/1999
UNITED KINGDOM 9922801.7 09/28/1999
UNITED KINGDOM 0000780.7 01/14/2000
UNITED KINGDOM PCT/GB00/00671 02/24/2000

If Required, Foreign Filing License Granted: 11/06/2003

Projected Publication Date: 03/18/2004

Non-Publication Request: No

Early Publication Request: No

Title

Dielectric layer for a semiconductor device and method of producing the same

**LICENSE FOR FOREIGN FILING UNDER
Title 35, United States Code, Section 184
Title 37, Code of Federal Regulations, 5.11 & 5.15**

GRANTED

The applicant has been granted a license under 35 U.S.C. 184, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" followed by a date appears on this form. Such licenses are issued in all applications where the conditions for issuance of a license have been met, regardless of whether or not a license may be required as set forth in 37 CFR 5.15. The scope and limitations of this license are set forth in 37 CFR 5.15(a) unless an earlier license has been issued under 37 CFR 5.15(b). The license is subject to revocation upon written notification. The date indicated is the effective date of the license, unless an earlier license of similar scope has been granted under 37 CFR 5.13 or 5.14.

This license is to be retained by the licensee and may be used at any time on or after the effective date thereof unless it is revoked. This license is automatically transferred to any related applications(s) filed under 37 CFR 1.53(d). This license is not retroactive.

The grant of a license does not in any way lessen the responsibility of a licensee for the security of the subject matter as imposed by any Government contract or the provisions of existing laws relating to espionage and the national security or the export of technical data. Licensees should apprise themselves of current regulations especially with respect to certain countries, of other agencies, particularly the Office of Defense Trade Controls, Department of State (with respect to Arms, Munitions and Implements of War (22 CFR 121-128)); the Office of Export Administration, Department of Commerce (15 CFR 370.10 (j)); the Office of Foreign Assets Control, Department of Treasury (31 CFR Parts 500+) and the Department of Energy.

NOT GRANTED

No license under 35 U.S.C. 184 has been granted at this time, if the phrase "IF REQUIRED, FOREIGN FILING LICENSE GRANTED" DOES NOT appear on this form. Applicant may still petition for a license under 37 CFR 5.12, if a license is desired before the expiration of 6 months from the filing date of the application. If 6 months has lapsed from the filing date of this application and the licensee has not received any indication of a secrecy order under 35 U.S.C. 181, the licensee may foreign file the application pursuant to 37 CFR 5.15(b).